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SUCCESSIVE DETECTION LOG VIDEO AMPLIFIER (SDLVA) WITH LIMITED RF OUTPUT, 1 - 26 GHz

Typical Applications

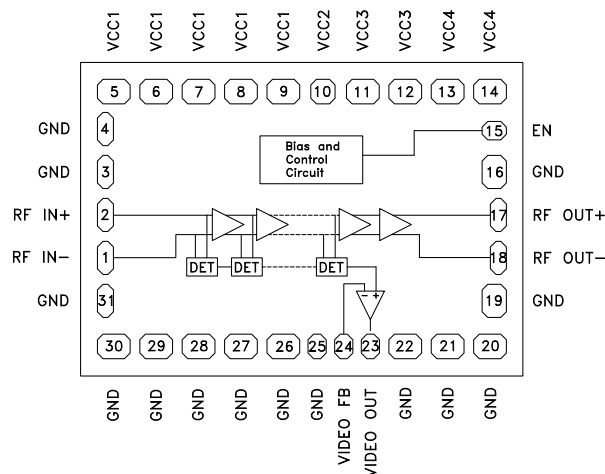
The HMC813 is ideal for:

- EW, ELINT & IFM Receivers
- DF Radar Systems
- ECM Systems
- Broadband Test & Measurement
- Power Measurement & Control Circuits
- Military & Space Applications

Features

- 1 to 26 GHz Operation
- High Logging Range: 55 dB
- Frequency Flatness: ± 1.5 dB
- Saturated Output Power: -7 dBm
- Fast Rise/Fall Times: 4/10 ns
- Single Positive Supply: +3.3V
- ESD Sensitivity (HBM): Class 1A
- 55 to +85° C Operating Temperature

Functional Diagram



General Description

The HMC813 is a Successive Detection Log Video Amplifier (SDLVA) With Limited RF which operates from 1 to 26 GHz. The HMC813 provides a logging range of 55 dB. This device offers typical fast rise/fall times of 4/10 ns. The HMC813 log video output slope is typically 14.5 mV/dB. Maximum recovery times are less than 20 ns. Ideal for high speed channelized receiver applications, the HMC813 operates from a single +3.3 V supply, and consumes only 150 mA. All data shown herein is measured with the chip in a 50 Ohm environment and contacted with RF probes.

Electrical Specifications, $T_A = +25^\circ\text{C}$, $V_{CC1} = V_{CC2} = V_{CC3} = V_{CC4} = 3.3\text{V}$ [1]

Parameter	Conditions	Typ.	Units
Input Frequency Range ^[2]		1 - 26	GHz
Frequency Flatness (Video out)	Pin= -25 dBm	± 1.5	dB
Log Linearity	Pin= -40 dBm to +0 dBm	± 1	dB
Log Linearity over Temperature	-55 to +85° C, Pin= -20 dBm	± 0.5	dB
Minimum Logging Range	to ± 3 dB error @ 18 GHz	-53	dBm
Maximum Logging Range	to ± 3 dB error @ 18 GHz	6	dBm
Saturated Output Power, Psat		-7	dBm
Saturated Output Power Flatness		± 2.5	dB
RF Input Return Loss		7	dB
RF Output Return Loss		13	dB
Log Video Minimum Output Voltage		0.875	V
Log Video Maximum Output Voltage		1.65	V
Log Video Output Rise Time	Pin = 0 dBm, 10% to 90%	4	ns
Log Video Output Fall Time	Pin = 0 dBm, 90% to 10%	10	ns

[1] Electrical specs and performance plots are given for single-ended operation.

[2] Video output load should be 1K Ohm or higher.



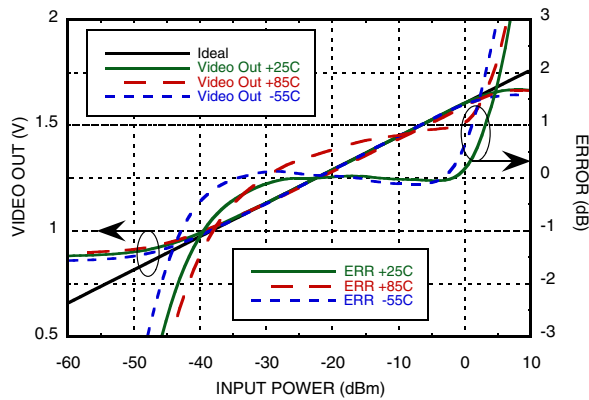
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Electrical Specifications, (continued) [1]

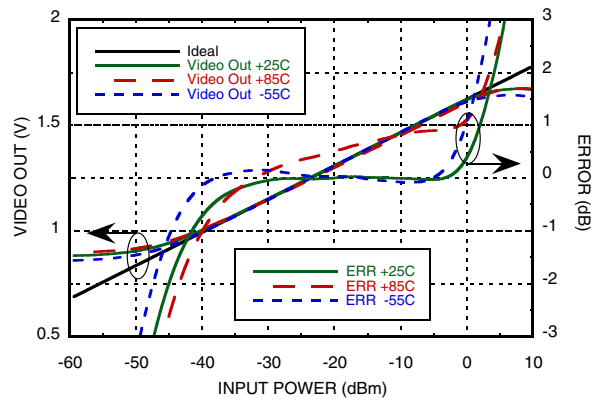
Parameter	Conditions	Typ.	Units
Log Video Recovery Time	-50 dBm to 0 dBm	20	ns
Log Video Output Slope		14.5	mV/dB
Log Video Output Slope Variation over Temperature	@ 10 GHz	3	$\mu\text{V}/\text{dB}^\circ\text{C}$
Log Video Propagation Delay		15	ns
Supply Current (I _{dc})		150	mA

[1] Electrical specs and performance plots are given for single-ended operation

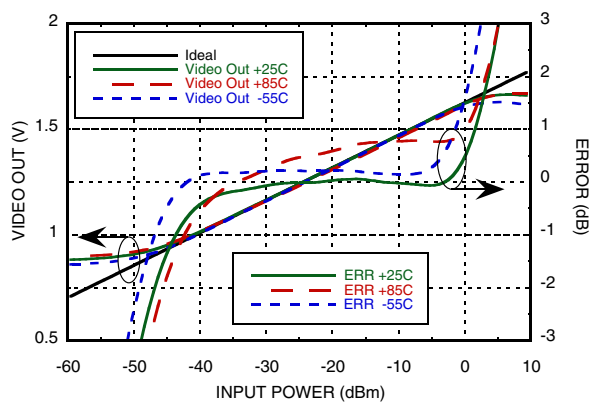
VIDEO OUT & Error vs. Input Power, Fin = 1 GHz [1]



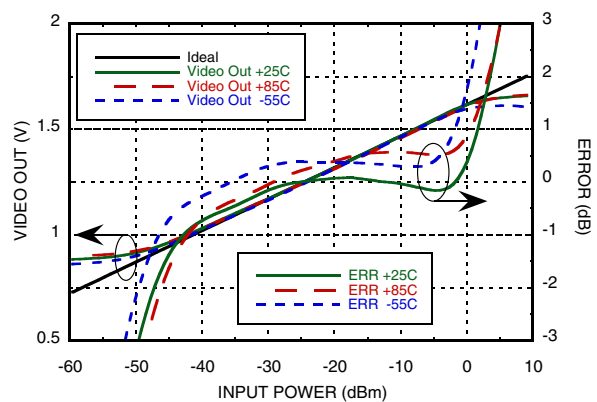
VIDEO OUT & Error vs. Input Power, Fin = 2 GHz [1]



VIDEO OUT & Error vs. Input Power, Fin = 6 GHz [1]



VIDEO OUT & Error vs. Input Power, Fin = 10 GHz [1]



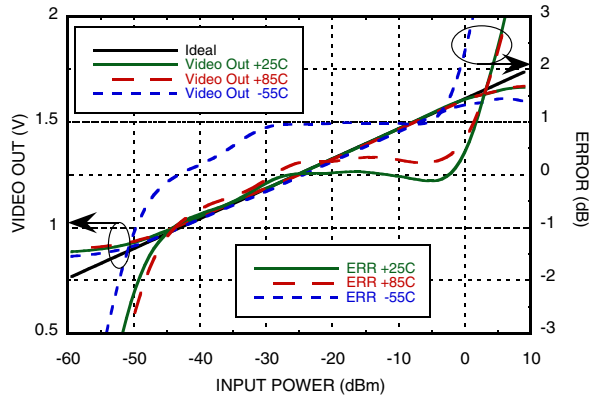
[1] Electrical specs and performance plots are given for single-ended operation



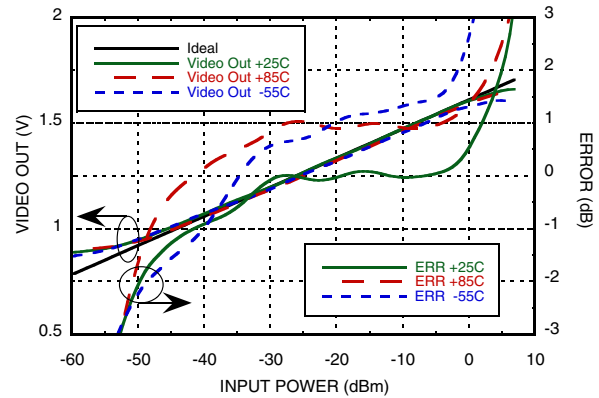
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POWER DETECTORS - CHIP

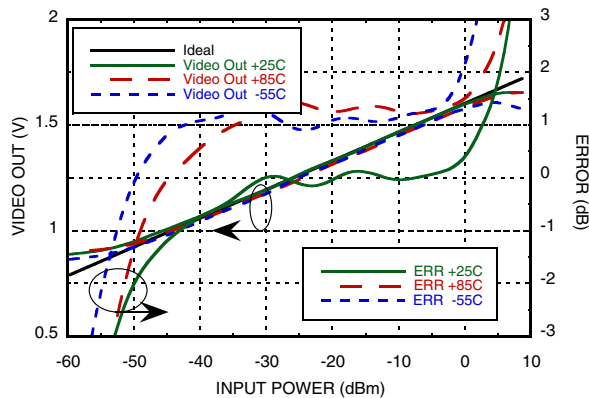
VIDEO OUT & Error vs. Input Power, $F_{in} = 14$ GHz ^[1]



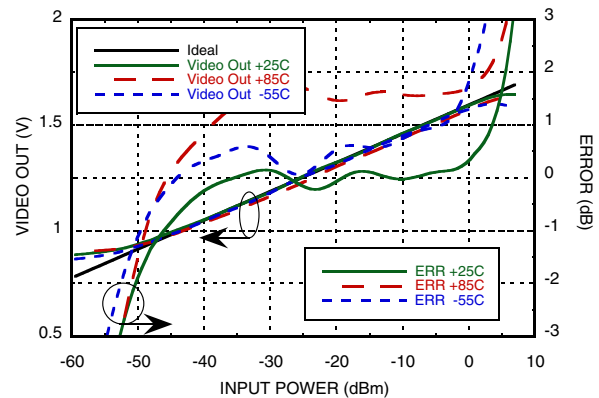
VIDEO OUT & Error vs. Input Power, $F_{in} = 18$ GHz ^[1]



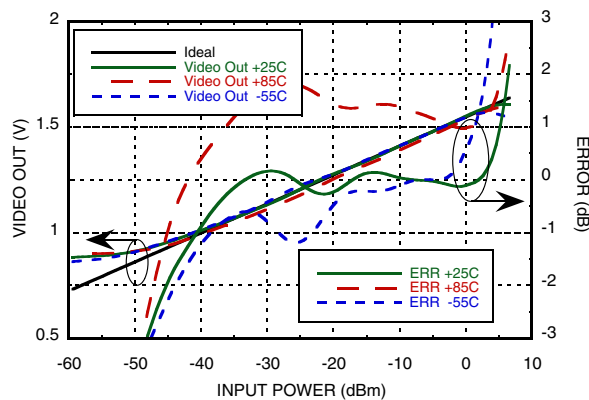
VIDEO OUT vs. Error vs. Input Power, $F_{in} = 20$ GHz ^[1]



VIDEO OUT & Error vs. Input Power, $F_{in} = 22$ GHz ^[1]



VIDEO OUT & Error vs. Input Power, $F_{in} = 26$ GHz ^[1]

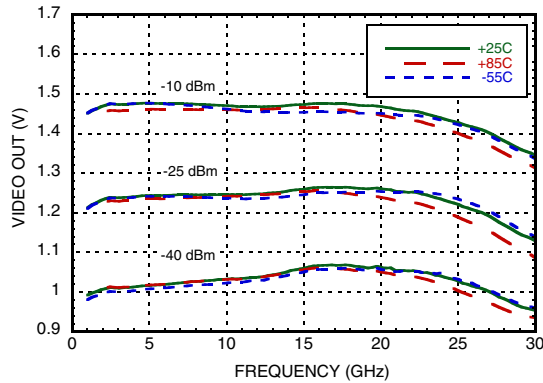


[1] Electrical specs and performance plots are given for single-ended operation

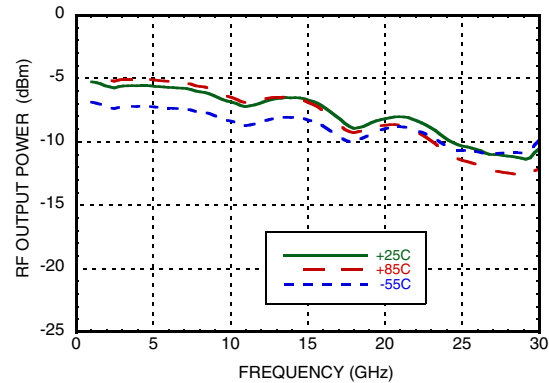


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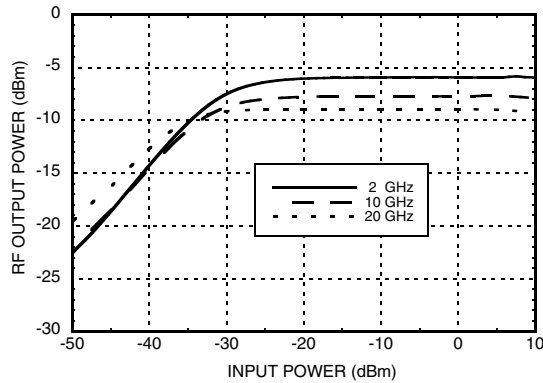
**VIDEO OUT vs. Frequency
Over Input Power & Temperature [1]**



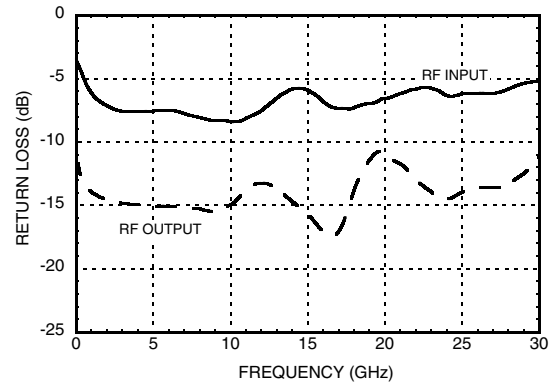
**Saturated RF Output Power vs. Frequency
Over Temperature @ Pin = -10 dBm [1]**



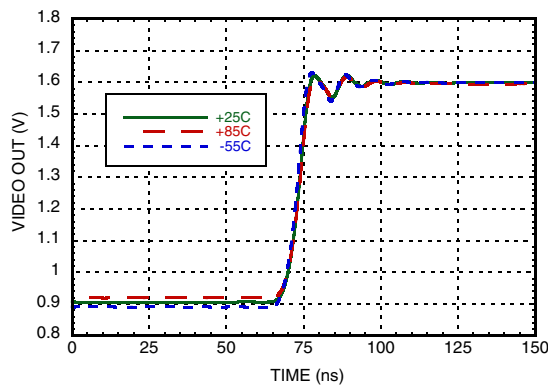
**RF Output Power vs. Input Power
Over Frequency [1]**



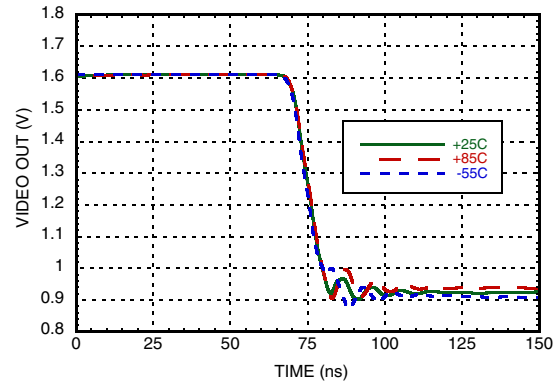
**Return Loss vs. Frequency
Over Temperature [1]**



**Rise Time @ Fin = 10 GHz @ Pin = 0 dBm
Over Temperature [1]**



**Fall Time @ Fin = 10 GHz @ Pin = 0 dBm
Over Temperature [1]**



[1] Electrical specs and performance plots are given for single-ended operation



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Absolute Maximum Ratings

Vcc1, Vcc2, Vcc3, Vcc4	+3.6V
ENBL	+3.6V
RF Input Power	+15 dBm
Channel Temperature	125 °C
Continuous P _{diss} (T=85°C) Derate 12.63 mW/°C above 85°C	0.51 W
Thermal Resistance (Channel to die bottom)	79.20 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C
ESD Sensitivity (HBM)	Class 1A

Die Packaging Information ^[1]

Standard	Alternate
WP-3 (Waffle Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.

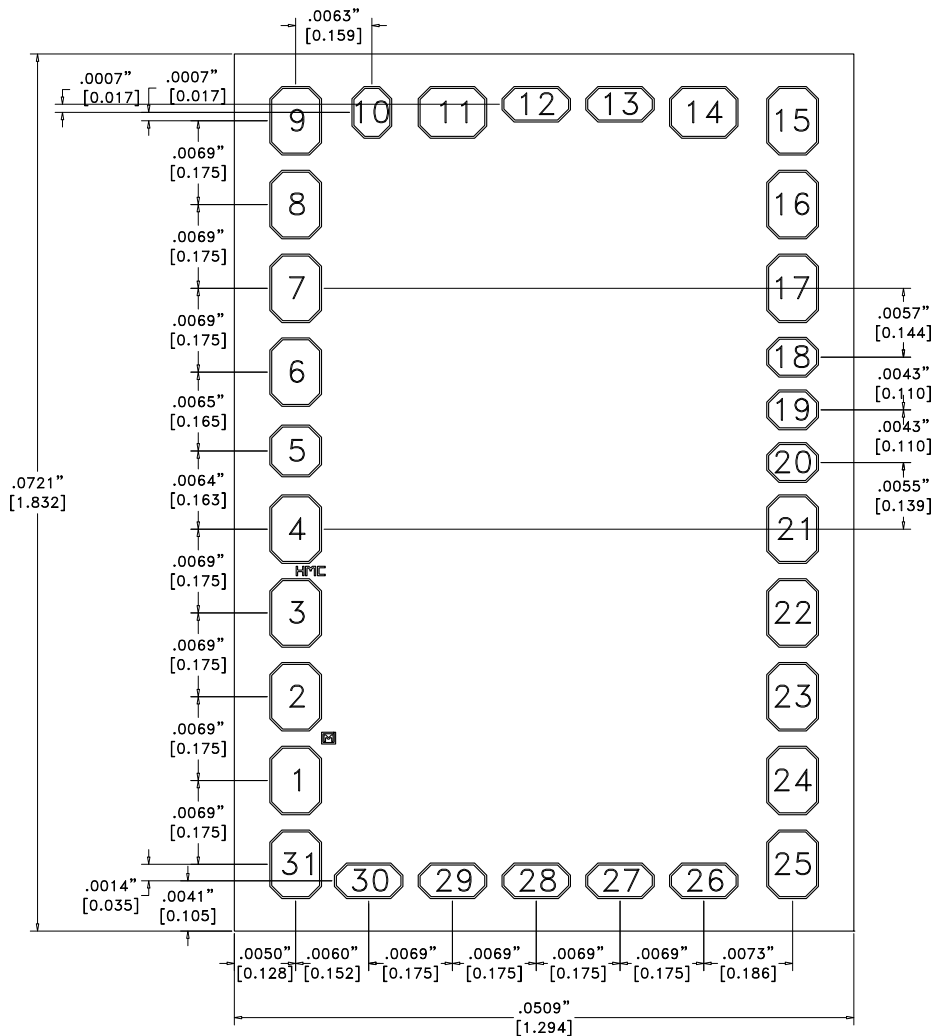
NOTES:

1. ALL DIMENSIONS IN INCHES [MILLIMETERS]
2. DIE THICKNESS IS 0.011 [0.28]
3. TYPICAL BOND PAD IS 0.0024 SQUARE
4. BOND PAD METALLIZATION: ALUMINUM
5. NO BACKSIDE METAL
6. NO CONNECTION REQUIRED FOR UNLABELED BOND PADS
7. OVERALL DIE SIZE IS ±.002

Outline Drawing



**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

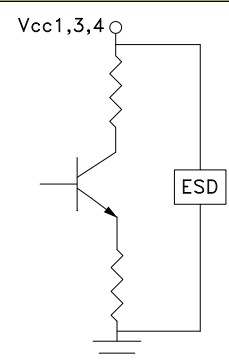
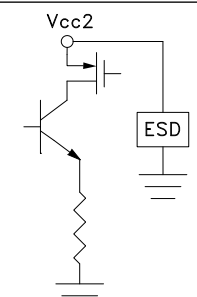
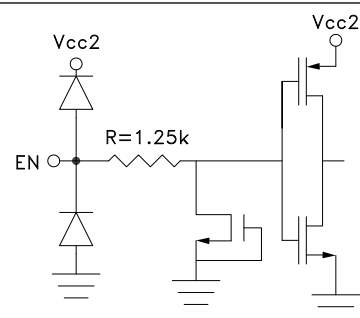

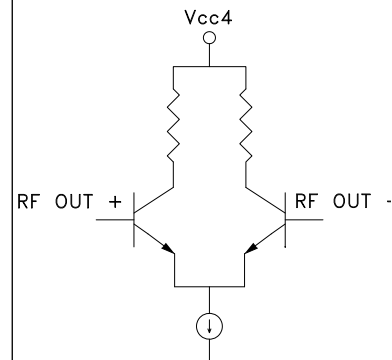


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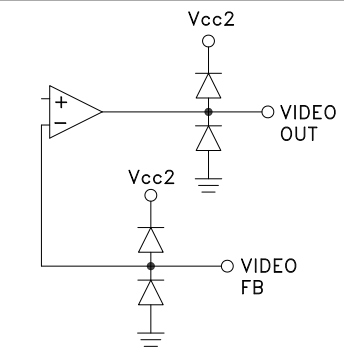
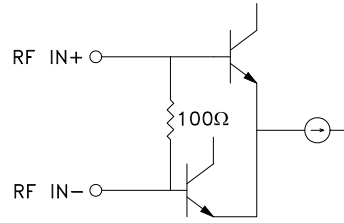
Pad Descriptions

Pad Number	Function	Description	Interface Schematic
1 -4, 31	VCC1	Bias supply. Connect supply voltage to these pads with appropriate filtering. See application circuit. To ensure proper start-up supply rise time should be faster than 100usec	
6, 7	VCC3		
8, 9	VCC4		
5	VCC2	Bias supply. Connect supply voltage to this pad with appropriate filtering. See application circuit. To ensure proper start-up supply rise time should be faster than 100usec	
10	EN	Enable pad, connected to supply voltage for normal operation. Total supply current reduced to less than 3mA when EN is set to 0V.	
11, 14 - 17, 20 - 26, 29, 30 Die Bottom	GND	Die bottom must be connected to RF and DC ground.	
12, 13	RFOUT+, RFOUT-	RF Output pads. AC couple RF to RF OUT+, and AC couple RF OUT- to ground via 50 Ohm for single ended operation.	



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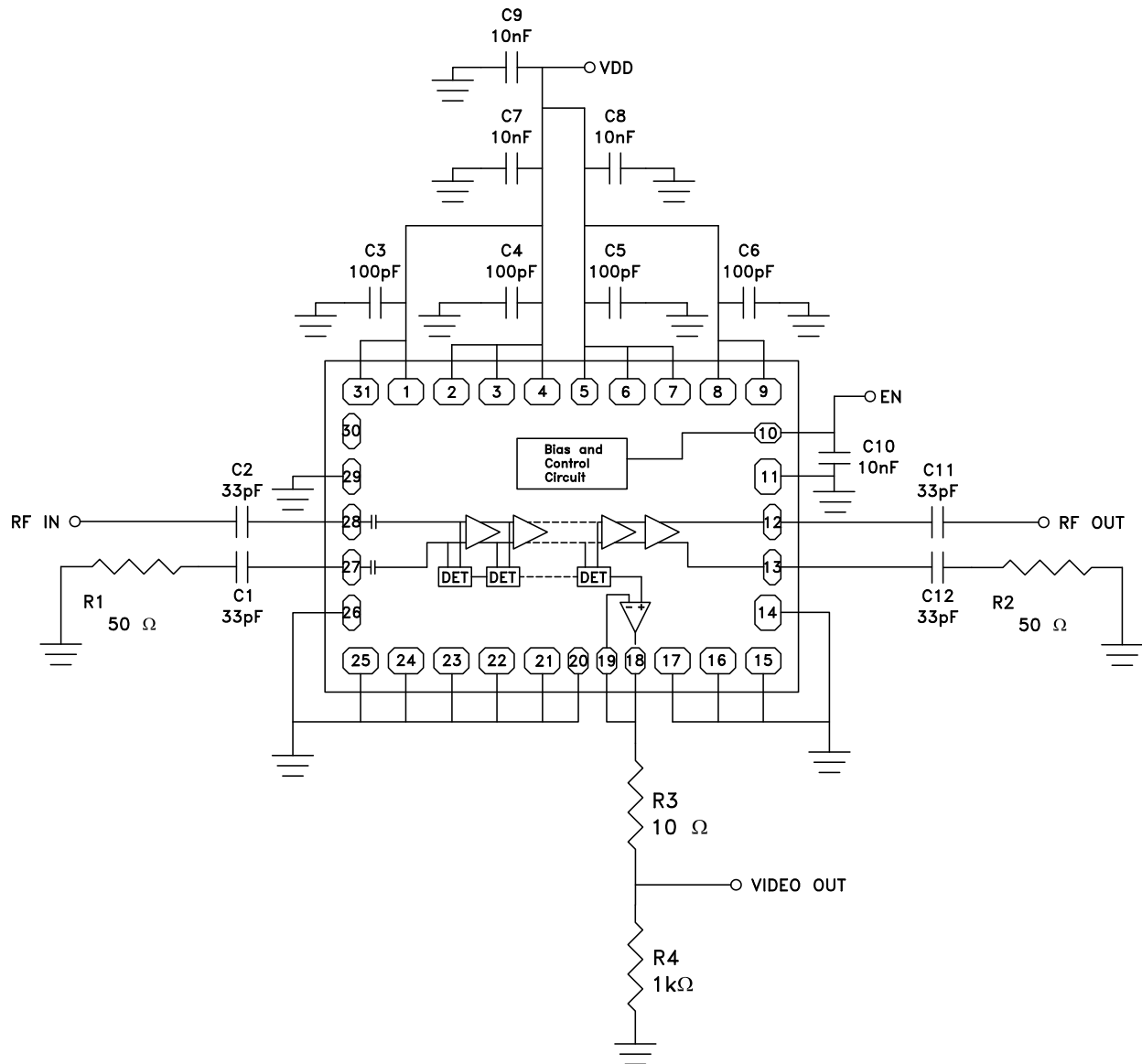
Pad Descriptions (Continued)

Pad Number	Function	Description	Interface Schematic
18, 19	VIDEO FB, VIDEO OUT	Video out and feedback. These pins should be shorted to each other (see application circuit). Video out load should be at least 1K Ohm or higher.	
27, 28	RFIN-, RFIN+	RF Input pads. Connect RF to RF IN+, and AC couple RF IN- to ground via 50 Ohm for single ended operation.	



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Application Circuit

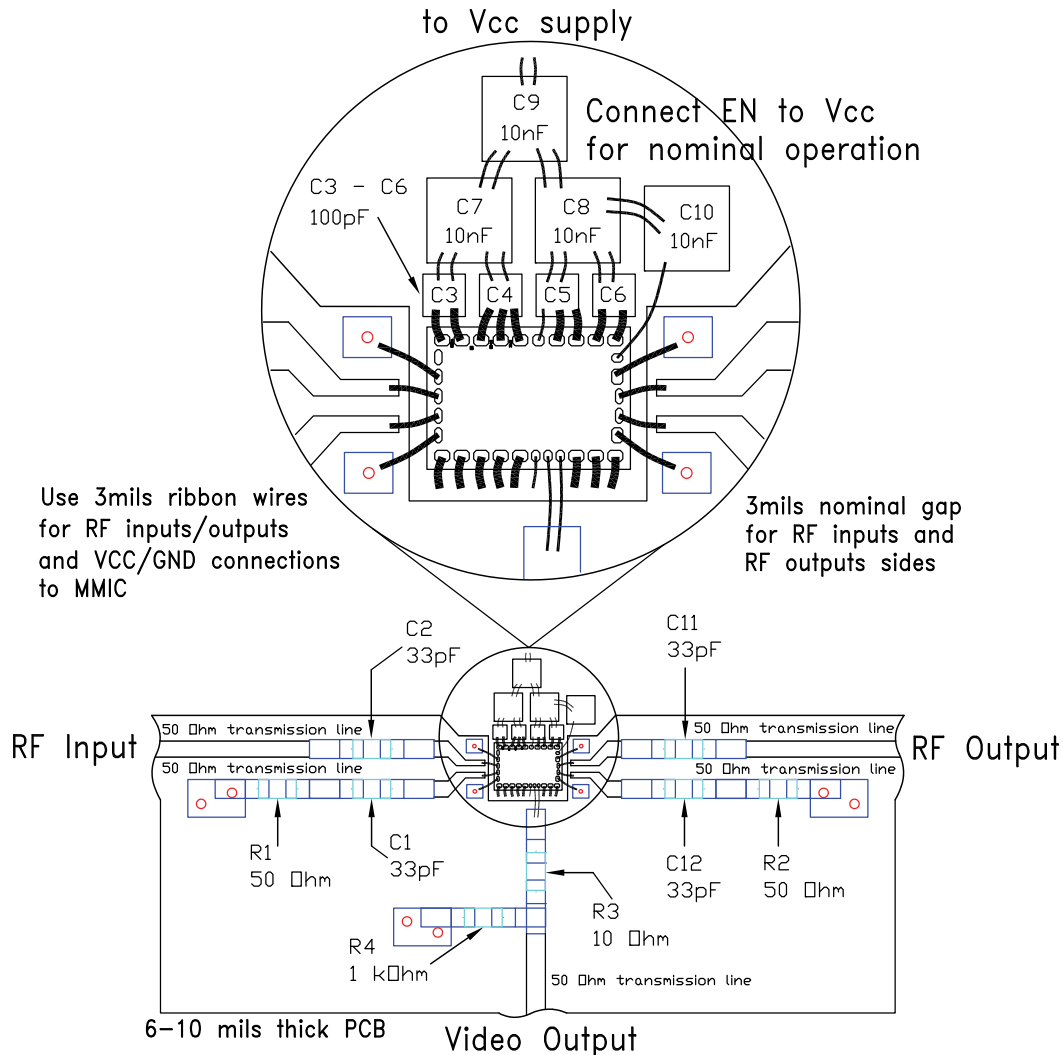


Note: Video output load should be 1K Ohm or higher.



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Assembly Diagram



List of Materials for Assembly Diagram

Item	Description
C3 - C6	100 pF SLC Capacitor, Presidio SA1212BX101M16VHXF
C7 - C10	10 nF SLC Capacitor, Presidio MVB3030X103ZGH5N
C1, C2, C11, C12	33 pF Capacitor, 0402 Pkg.
R1, R2	50 Ohm Resistor, 0402 Pkg.
R3	10 Ohm Resistor, 0402 Pkg.
R4	1k Ohm Resistor, 0402 Pkg.
U1	HMC813 Die



**ELECTROSTATIC SENSITIVE DEVICE
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Mounting & Bonding Techniques for MMICs

The die should be attached directly to the ground plane with epoxy (see HMC general Handling, Mounting, Bonding Note).

50 Ohm Microstrip transmission lines on 0.254mm (10 mil) thick alumina thin film substrates are recommended for bringing RF to and from the chip (Figure 1).

Microstrip substrates should be placed as close to the die as possible in order to minimize bond wire length. Typical die-to-substrate spacing is 0.076mm to 0.152 mm (3 to 6 mils).

Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

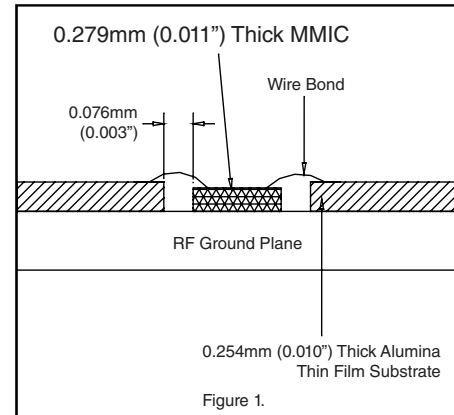
Static Sensitivity: Follow ESD precautions to protect against ESD strikes. HMC813 is a Class-1A ESD sensitive part. Observe handling precautions.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: The chip may be handled by a vacuum collet or with a sharp pair of tweezers.

Mounting

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.





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- Техническая поддержка проекта;
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